

# R1QKA4436RBG,R1QKA4418RBG

# 144-Mbit QDR™II+ SRAM 4-word Burst Architecture(2.0 Cycle Read latency) with ODT

R10DS0138EJ0202 Rev.2.02 Aug 01, 2014

### **Description**

The R1QKA4436RBG is a 4,194,304-word by 36-bit and the R1QKA4418RBG is a 8,388,608-word by 18-bit synchronous quad data rate static RAM fabricated with advanced CMOS technology using full CMOS six-transistor memory cell. It integrates unique synchronous peripheral circuitry and a burst counter. All input registers are controlled by an input clock pair (K and /K) and are latched on the positive edge of K and /K. These products are suitable for applications which require synchronous operation, high speed, low voltage, high density and wide bit configuration. These products are packaged in 165-pin plastic FBGA package.

#### **Features**

- Power Supply
  - 1.8 V for core  $(V_{DD})$ , 1.4 V to  $V_{DD}$  for I/O  $(V_{DDO})$
- Clock
  - Fast clock cycle time for high bandwidth
  - Two input clocks (K and /K) for precise DDR timing at clock rising edges only
  - Two output echo clocks (CQ and /CQ) simplify data capture in high-speed systems
  - Clock-stop capability with us restart
- **■** I/O
  - Separate independent read and write data ports with concurrent transactions
  - 100% bus utilization DDR read and write operation
  - HSTL I/O
  - User programmable output impedance
  - PLL circuitry for wide output data valid window and future frequency scaling
  - Data valid pin (QVLD) to indicate valid data on the output
- Function
  - Four-tick burst for reduced address frequency
  - Internally self-timed write control
  - Simple control logic for easy depth expansion
  - JTAG 1149.1 compatible test access port
- Package
  - 165 FBGA package (15 x 17 x 1.4 mm)

# **Part Number Definition**

Column No.	0	1	2	3	4	5	6	7	8	9	10	11	-	12	13	14	15	16
Example	R	1	Q	K	A	4	4	3	6	R	В	G	-	2	5	I	В	0
	The a	above	part nu	ımber	is just	examp	le for	144M (	QDRII-	+ B4 x3	36 400	MHz,	15x17r	nm PK	G, Pb	free p	art.	

No.	-	Comments	No.	-	Comments	No.	-	Comments
0-1	R1	Renesas Memory Prefix	4	Α	Vdd = 1.8 V		60	Frequency = 167MHz
	Q2	QDR    B2 <sup>[*1]</sup> (L15) <sup>[*2]</sup>		36	Density = 36Mb		50	Frequency = 200MHz
	Q3	QDR    B4 (L15)	5-6	72	Density = 72Mb		40	Frequency = 250MHz
	Q4	DDR II B2 (L15)	0 0	44	Density = 144Mb		36	Frequency = 275MHz
	Q5	DDR II B4 (L15)		88	Density = 288Mb		33	Frequency = 300MHz
	Q6	DDR II B2 SIO <sup>[*3]</sup> (L15)		09	Data width = 9bit	12-13	30	Frequency = 333MHz
	QA	QDR II+ B4 L25 <sup>[*2]</sup>	7-8	18	Data width = 18bit	12-13	27	Frequency = 375MHz
	QB	DDR II+ B2 L25		36	Data width = 36bit		25	Frequency = 400MHz
	QC	DDR II+ B4 L25		R	1st Generation		22	Frequency = 450MHz
	QD	QDR II+ B4 L25 w/ODT[*4]		Α	2nd Generation		20	Frequency = 500MHz
	QE	DDR II+ B2 L25 w/ODT	9	В	3rd Generation		19	Frequency = 533MHz
2-3	QF	DDR II+ B4 L25 w/ODT		С	4th Generation		18	Frequency = 550MHz
	QG	QDR II+ B4 L20		D	5th Generation		R	Commercial temp.
	QH	DDR II+ B2 L20		Е	6th Generation	14	11	Ta range = 0°C to 70°C
	QJ	DDR II+ B4 L20		F	7th Generation	17	1	Industrial temp.
	QK	QDR II+ B4 L20 w/ODT	10-11	BG	PKG= BGA 15x17 mm		'	Ta range = -40℃ to 85℃
	QL	DDR II+ B2 L20 w/ODT	10-11	BB	PKG= BGA 13x15 mm		Α	Pb and Tray
	QM	DDR II+ B4 L20 w/ODT				15	В	Pb-free and Tray
	QN	QDR II+ B2 L20				13	T	Pb and Tape&Reel
	QP						S	Pb-free and Tape&Reel
			_	_	-		0 to 9,	
	-	-				16	A to Z	Renesas internal use
							or None	

Note1:

[\*1] B=Burst length (B2: Burst length=2, B4: Burst length=4)
[\*2] L=Read Latency (L15: Read Latency = 1.5 cycle, L20: 2.0 cycle, L25: 2.5 cycle)

[\*3] SIO=Separate I/O [\*4] ODT=On die termination

Note2: Package Marking Name

Pb parts: Marking Name = Part Number(0-14)

Pb-free parts: Marking Name = Part Number(0-14) + "PB-F" (Example) R1QAA4436RBG-20R R1QAA4436RBG-20R ----- Pb parts R1QAA4436RBG-20R PB-F ----- Pb-free parts

Note3: : RoHS Compliance Level = 5/6

Pb-free: RoHS Compliance Level = 6/6

Note4: R1Q\*A series support both "Commercial" and "Industrial" temperatures

by "Industrial" temperature parts.

# **Part Number Information**

Ordering part number	Organization (word x bit)	Cycle time	Clock frequency	Operating Ambient Temperature	Core Supply Voltage (V)	Package
R1QKA4436RBG-25IA0	4M x 36	2.50ns	400MHz	$T_A = -40 \text{ to } 85^{\circ}\text{C}$	1.8 ± 0.1	165-pin PLASTIC BGA
R1QKA4418RBG-25IA0	8M x 18	2.50ns	400MHz			(15 x 17) Pb
R1QKA4436RBG-25IB0	4M x 36	2.50ns	400MHz	$T_A = -40 \text{ to } 85^{\circ}\text{C}$	1.8 ± 0.1	165-pin PLASTIC BGA
R1QKA4418RBG-25IB0	8M x 18	2.50ns	400MHz			(15 x 17) Pb-free

# **Pin Arrangement**

# [R1QKA4436RBG]

4M x 36 (Top View)

_	1	2	3	4	5	6	7	8	9	10	11
Α	/CQ	NC	SA	/W	/BW2	/K	/BW1	/R	SA	SA	CQ
В	Q27	Q18	D18	SA	/BW3	K	/BW0	SA	D17	Q17	Q8
С	D27	Q28	D19	Vss	SA	NC	SA	Vss	D16	Q7	D8
D	D28	D20	Q19	Vss	Vss	Vss	Vss	Vss	Q16	D15	D7
Ε	Q29	D29	Q20	$V_{DDQ}$	Vss	Vss	Vss	$V_{DDQ}$	Q15	D6	Q6
F	Q30	Q21	D21	$V_{DDQ}$	<b>V</b> DD	Vss	<b>V</b> DD	$V_{DDQ}$	D14	Q14	Q5
G	D30	D22	Q22	$V_{DDQ}$	<b>V</b> DD	Vss	<b>V</b> DD	$V_{DDQ}$	Q13	D13	D5
Н	/DOFF	VREF	$V_{DDQ}$	$V_{DDQ}$	<b>V</b> DD	Vss	<b>V</b> DD	$V_{DDQ}$	$V_{DDQ}$	VREF	ZQ
J	D31	Q31	D23	$V_{DDQ}$	<b>V</b> DD	Vss	<b>V</b> DD	$V_{DDQ}$	D12	Q4	D4
K	Q32	D32	Q23	$V_{DDQ}$	<b>V</b> DD	Vss	<b>V</b> DD	$V_{DDQ}$	Q12	D3	Q3
L	Q33	Q24	D24	$V_{DDQ}$	Vss	Vss	Vss	$V_{DDQ}$	D11	Q11	Q2
M	D33	Q34	D25	Vss	Vss	Vss	Vss	Vss	D10	Q1	D2
N	D34	D26	Q25	Vss	SA	SA	SA	Vss	Q10	D9	D1
Р	Q35	D35	Q26	SA	SA	QVLD	SA	SA	Q9	D0	Q0
R	TDO	TCK	SA	SA	SA	ODT	SA	SA	SA	TMS	TDI

Notes: 1. Address expansion order for future higher density SRAMs:  $10A \rightarrow 2A \rightarrow 7A \rightarrow 5B$ .

2. NC pins can be left floating or connected to 0V to  $V_{\text{DDQ}}$ 

# [R1QKA4418RBG]

8M x 18 (Top View)

	1	2	3	4	5	6	7	8	9	10	11
Α	/CQ	SA	SA	/W	/BW1	/K	NC	/R	SA	SA	CQ
В	NC	Q9	D9	SA	NC	K	/BW0	SA	NC	NC	Q8
С	NC	NC	D10	Vss	SA	NC	SA	Vss	NC	Q7	D8
D	NC	D11	Q10	Vss	Vss	Vss	Vss	Vss	NC	NC	D7
Ε	NC	NC	Q11	$V_{DDQ}$	Vss	Vss	Vss	$V_{DDQ}$	NC	D6	Q6
F	NC	Q12	D12	$V_{DDQ}$	<b>V</b> DD	Vss	<b>V</b> DD	$V_{DDQ}$	NC	NC	Q5
G	NC	D13	Q13	$V_{DDQ}$	<b>V</b> DD	Vss	<b>V</b> DD	$V_{DDQ}$	NC	NC	D5
н	/DOFF	VREF	$V_{DDQ}$	$V_{DDQ}$	<b>V</b> DD	Vss	<b>V</b> DD	$V_{DDQ}$	$V_{DDQ}$	VREF	ZQ
J	NC	NC	D14	$V_{DDQ}$	<b>V</b> DD	Vss	<b>V</b> DD	$V_{DDQ}$	NC	Q4	D4
	NC NC	NC NC	D14 Q14	V <sub>DDQ</sub>	V <sub>DD</sub>	Vss Vss	V <sub>DD</sub>	V <sub>DDQ</sub>	NC NC	Q4 D3	D4 Q3
J											
J K	NC	NC	Q14	V <sub>DDQ</sub>	<b>V</b> DD	Vss	<b>V</b> DD	$V_{DDQ}$	NC	D3	Q3
J K L	NC NC	NC Q15	Q14 D15	V <sub>DDQ</sub>	V <sub>DD</sub> Vss	Vss Vss	V <sub>DD</sub> Vss	V <sub>DDQ</sub>	NC NC	D3 NC	Q3 Q2
J K L	NC NC	NC Q15 NC	Q14 D15 D16	V <sub>DDQ</sub> V <sub>DDQ</sub> Vss	V <sub>DD</sub> Vss Vss	Vss Vss Vss	V <sub>DD</sub> Vss Vss	V <sub>DDQ</sub> V <sub>DDQ</sub> Vss	NC NC	D3 NC Q1	Q3 Q2 D2

Notes: 1. Address expansion order for future higher density SRAMs:  $10A \rightarrow 2A \rightarrow 7A \rightarrow 5B$ .

2. NC pins can be left floating or connected to 0V to  $V_{DDQ}$ 

# **Pin Descriptions**

Name	I/O type	Descriptions	Note
SA	Input	Synchronous address inputs: These inputs are registered and must meet the setup and hold times around the rising edge of K (read and write address). These inputs are ignored when device is deselected.	
/R	Input	Synchronous read: When low, this input causes the address inputs to be registered and a READ cycle to be initiated. This input must meet setup and hold times around the rising edge of K, and is ignored on the subsequent rising edge of K.	
/W	Input	Synchronous write: When low, this input causes the address inputs to be registered and a WRITE cycle to be initiated. This input must meet setup and hold times around the rising edge of K, and is ignored on the subsequent rising edge of K.	
/BW <sub>x</sub>	Input	Synchronous byte writes: When low, these inputs cause their respective byte to be registered and written during WRITE cycles. These signals are sampled on the same edge as the corresponding data and must meet setup and hold times around the rising edges of K and /K for each of the two rising edges comprising the WRITE cycle. See Byte Write Truth Table for signal to data relationship.	
K, /K	Input	Input clock: This input clock pair registers address and control inputs on the rising edge of K, and registers data on the rising edge of K and the rising edge of /K. /K is ideally 180 degrees out of phase with K. All synchronous inputs must meet setup and hold times around the clock rising edges. These balls cannot remain V <sub>REF</sub> level.	
/DOFF	Input	PLL disable: When low, this input causes the PLL to be bypassed for stable, low frequency operation.	
TMS TDI	Input	IEEE1149.1 test inputs: 1.8 V I/O levels. These balls may be left unconnected if the JTAG function is not used in the circuit.	
TCK	Input	IEEE1149.1 clock input: 1.8 V I/O levels. This ball must be tied to $V_{\rm SS}$ if the JTAG function is not used in the circuit.	
ZQ	Input	Output impedance matching input: This input is used to tune the device outputs to the system data bus impedance. Q and CQ output impedance are set to $0.2 \times RQ$ , where RQ is a resistor from this ball to ground. This ball can be connected directly to $V_{DDQ}$ , which enables the minimum impedance mode. This ball cannot be connected directly to $V_{SS}$ or left unconnected. The ODT termination values tracks the value of RQ. The ODT range is selected by ODT control input.	
ODT	Input	ODT control: When low;	
		Low range mode is selected. The impedance range is between 52 $\Omega$ and 105 $\Omega$ (Thevenin equivalent), which follows $0.3 \times RQ$ for 175 $\Omega \le RQ \le 350 \Omega$ .	
		ODT control:When high;	
		High range mode is selected. The impedance range is between 105 $\Omega$ and 150 $\Omega$ (Thevenin equivalent), which follows $0.6 \times RQ$ for 175 $\Omega \le RQ \le 250 \Omega$ .	
		ODT control:When floating;	
		High range mode is selected.	

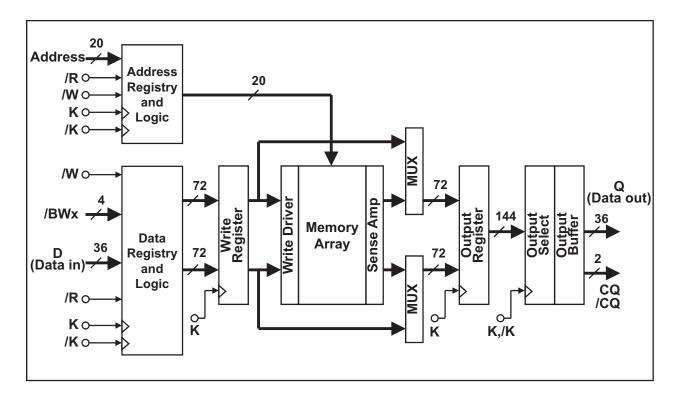
Name	I/O type	Descriptions	Note
D <sub>0</sub> to D <sub>n</sub>	Input	Synchronous data inputs: Input data must meet setup and hold times around the rising edges of K and /K during WRITE operations. See Pin Arrangement figures for ball site location of individual signals.  The ×18 device uses D0 to D17. D18 to D35 should be treated as NC pin.  The ×36 device uses D0 to D35.	
CQ, /CQ	Output	Synchronous echo clock outputs: The edges of these outputs are tightly matched to the synchronous data outputs and can be used as a data valid indication. These signals run freely and do not stop when Q tri-states.	
TDO	Output	IEEE 1149.1 test output: 1.8 V I/O level.	
Q <sub>0</sub> to Q <sub>n</sub>	Output	Synchronous data outputs: Output data is synchronized to the K clock. This bus operates in response to /R commands. See Pin Arrangement figures for ball site location of individual signals.  The ×18 device uses Q0 to Q17. Q18 to Q35 should be treated as NC pin.  The ×36 device uses Q0 to Q35.	
QVLD	Output	Valid output indicator: The Q Valid indicates valid output data. QVLD is edge aligned with CQ and /CQ.	
V <sub>DD</sub>	Supply	Power supply: 1.8 V nominal. See DC Characteristics and Operating Conditions for range.	1
$V_{DDQ}$	Supply	Power supply: Isolated output buffer supply. Nominally 1.5 V. See DC Characteristics and Operating Conditions for range.	1
V <sub>SS</sub>	Supply	Power supply: Ground.	1
V <sub>REF</sub>	-	HSTL input reference voltage: Nominally V <sub>DDQ</sub> /2, but may be adjusted to improve system noise margin. Provides a reference voltage for the HSTL input buffers.	
NC	-	No connect: These pins can be left floating or connected to 0V to V <sub>DDQ</sub> .	

#### Notes:

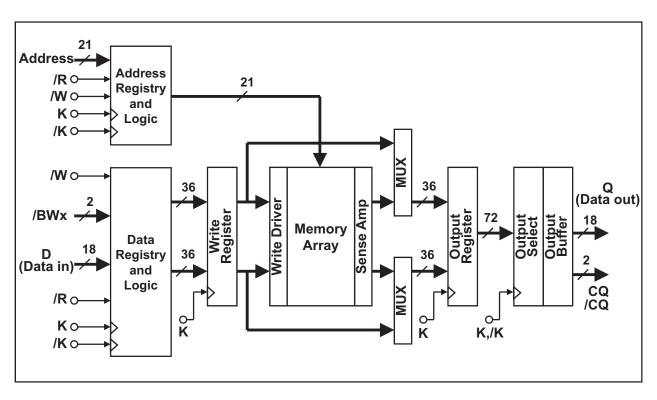
1. All power supply and ground balls must be connected for proper operation of the device.

# **Block Diagram**

#### [R1QKA4436RBG]



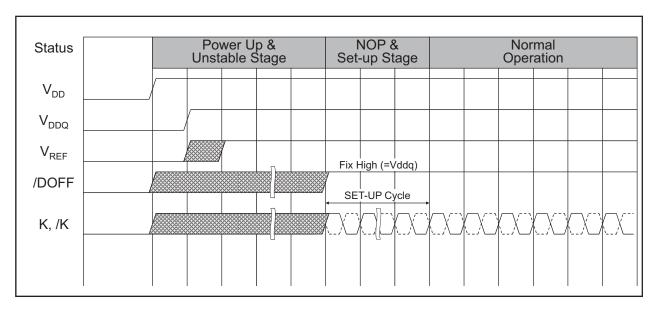
### [R1QKA4418RBG]



# **Power-up and Initialization Sequence**

V<sub>DD</sub> must be stable before K, /K clocks are applied.

- Recommended voltage application sequence :  $V_{SS} \rightarrow V_{DD} \rightarrow V_{DDQ}$  &  $V_{REF} \rightarrow V_{IN}$ . (0 V to  $V_{DD}$ ,  $V_{DDQ} <$  200 ms)
- Apply  $V_{REF}$  after  $V_{DDQ}$  or at the same time as  $V_{DDQ}$ .
- Then execute either one of the following sequences.
- 1. Single Clock Mode
  - Drive /DOFF high (/DOFF can be tied high from the start).
  - Then provide stable clocks (K, /K) for at least 20 us.



#### 2. PLL Off Mode (/DOFF tied low)

- In the "NOP and setup stage", provide stable clocks (K, /K) for at least 20 us.

### **PLL Constraints**

- 1. These chips use the PLL. The clock input should have low phase jitter which is specified as tKC var.
- 2. The lower end of the frequency at which the PLL can operate is 250 MHz. (Please refer to AC Characteristics table for detail.)
- 3. When the operating frequency is changed or /DOFF level is changed, setup cycles are required again.

# **Programmable Output Impedance**

1. Output buffer impedance can be programmed by terminating the ZQ ball to  $V_{SS}$  through a precision resistor (RQ). The value of RQ is five times the output impedance desired. The allowable range of RQ to guarantee impedance matching with a tolerance of 15% is between 175  $\Omega$  and 350  $\Omega$ . The total external capacitance of ZQ ball must be less than 7.5 pF.

### QVLD (Valid data indicator)

1. QVLD is provided on the QDR-II+ and DDR-II+ to simplify data capture on high speed systems. The Q Valid indicates valid output data. QVLD is activated half cycle before the read data for the receiver to be ready for capturing the data. QVLD is inactivated half cycle before the read finish for the receiver to stop capturing the data. QVLD is edge aligned with CQ and /CQ.

# **ODT (On Die Termination)**

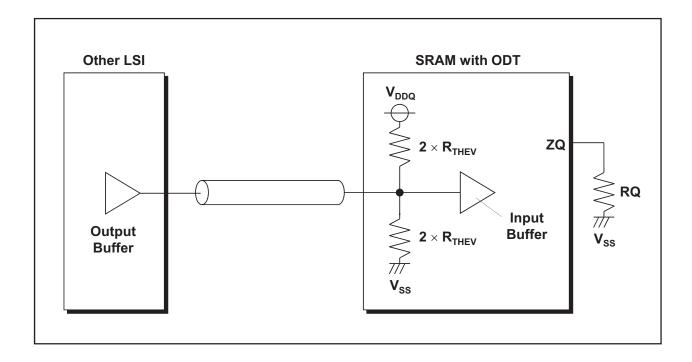
- 1. To reduce reflection which produces noise and lowers signal quality, the signals should be terminated, especially at high frequency. Renesas offers ODT on the input signals to QDR-II+ and DDR-II+ family of devices.
- 2. The ODT termination values tracks the value of RQ. The ODT range is selected by ODT control input.
- 3. In DDR-II+ devices having common I/O bus, ODT is automatically enabled when the device inputs data and disabled when the device outputs data.
- 4. There is no difference in AC timing characteristics between the SRAMs with ODT and SRAMs without ODT.
- 5. There is no increase in the  $I_{DD}$  of SRAMs with ODT, however, there is an increase in the  $I_{DDQ}$  (current consumption from the I/O voltage supply) with ODT.

#### **ODT** range

ODT control pin	Thevenin equivalent resistance (R <sub>THEV</sub> )	Unit	Notes
Low	0.3 x RQ	Ω	1,3
High	0.6 x RQ	Ω	2
Floating	0.6 x RQ	Ω	2

- 1. Allowable range of RQ for Option 1 to guarantee impedance matching a tolerance of  $\pm$  20 % is 175  $\Omega \le$  RQ  $\le$  350  $\Omega$ .
- 2. Allowable range of RQ to guarantee impedance matching a tolerance of  $\pm$  20 % is 175  $\Omega \le RQ \le 250 \Omega$ .
- 3. ODT control pin is connected to  $V_{DD}Q$  through 3.5 k $\Omega$ . Therefore it is recommended to connect it to  $V_{SS}$  through less than 100  $\Omega$  to make it low.

# Thevenin termination



# **ODT** pin

Pin name	ODT On/Off
D <sub>0</sub> to D <sub>n</sub>	Always On
/BW <sub>x</sub>	Always On
K, /K	Always On

#### **K Truth Table**

Operation	K	/R	/W	D or Q				
W. ''. O. I.				Data in				
Write Cycle:				Input	D(A+0)	D(A+1)	D(A+2)	D(A+3)
Load address, input write data on two consecutive	<b>↑</b>	H*7	L*8	data	D(A:0)	D(A: 1)	D(A:2)	D(A:3)
K and /K rising edges				Input	K(t+1) ↑	/K(t+1) ↑	K(t+2) ↑	/K(t+2) ↑
3 3 3 3 3				clock	K((+1)	/K((+1)	Κ((+2)	/K(t+2)
				Data out		•		
Read Cycle:				Output	0(4.10)	0(4.11)	0(4+2)	0(4+2)
Load address, output read data on two consecutive	<b>↑</b>	L*8	×	data	Q(A+0)	Q(A+1)	Q(A+2)	Q(A+3)
K and /K rising edges				Input	K(t+2) ↑	/K(t+2) ↑	K(t+3) ↑	/K(t+3) ↑
				clock	Ι((: 2)	/1((1.2)	Ι (((.0)	/14(1:3)
NOP (No operation)	1	Н	Н	D = x or	Q = High-	Z	•	<u>'</u>
Standby (Clock stopped)	Stopped	Х	Х	Previous	state			

- 1. H: high level, L: low level, ×: don't care, ↑: rising edge.
- 2. Data inputs are registered at K and /K rising edges. Data outputs are delivered at K clock edges.
- 3. /R and /W must meet setup/hold times around the rising edges (low to high) of K and are registered at the rising edge of K.
- 4. This device contains circuitry that will ensure the outputs will be in high-Z during power-up.
- 5. Refer to state diagram and timing diagrams for clarification.
- 6. When clocks are stopped, the following cases are recommended; the case of K = low, /K = high, or the case of K = high, /K = low. This condition is not essential, but permits most rapid restart by overcoming transmission line charging symmetrically.
- 7. If this signal was low to initiate the previous cycle, this signal becomes a "don't care" for this operation; however, it is strongly recommended that this signal be brought high, as shown in the truth table.
- 8. This signal was high on previous K clock rising edge. Initiating consecutive READ or WRITE operations on consecutive K clock rising edges is not permitted. The device will ignore the second request.

# Byte Write Truth Table (x 36)

Operation	K	/K	/BW0	/BW1	/BW2	/BW3
Write D0 to D35	1	-	L	L	L	L
	-	1	L	L	L	L
Write D0 to D8	1	-	L	Н	Н	Н
	-	1	L	Н	Н	Н
Write D9 to D17	1	-	Н	L	Н	Н
	-	1	Н	L	Н	Н
Write D18 to D26	1	-	Н	Н	L	Н
	-	1	Н	Н	L	Н
Write D27 to D35	1	-	Н	Н	Н	L
	-	1	Н	Н	Н	L
Write nothing	1	-	Н	Н	Н	Н
	-	1	Н	Н	Н	Н

#### Notes:

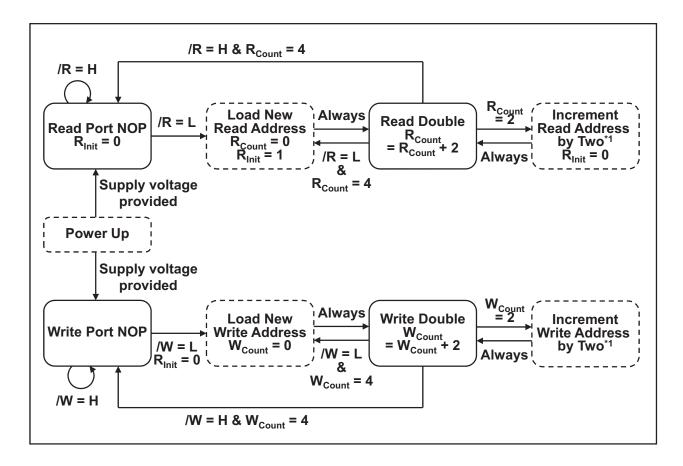
- 1. H: high level, L: low level, ↑: rising edge.
- 2. Assumes a WRITE cycle was initiated. /BWx can be altered for any portion of the BURST WRITE operation provided that the setup and hold requirements are satisfied.

# Byte Write Truth Table (x 18)

Operation	К	/K	/BW0	/BW1
Write D0 to D17	1	-	L	L
	-	<b>↑</b>	L	L
Write D0 to D8	1	-	L	Н
	-	<b>↑</b>	L	Н
Write D9 to D17	1	-	Н	L
	-	<b>↑</b>	Н	L
Write nothing	1	-	Н	Н
	-	1	Н	Н

- 1. H: high level, L: low level, ↑: rising edge.
- 2. Assumes a WRITE cycle was initiated. /BWx can be altered for any portion of the BURST WRITE operation provided that the setup and hold requirements are satisfied.

# **Bus Cycle State Diagram**



- 1. The address is concatenated with two additional internal LSBs to facilitate burst operation. The address order is always fixed as: xxx...xxx+0, xxx...xxx+1, xxx...xxx+2, xxx...xxx+3.

  Bus cycle is terminated at the end of this sequence (burst count = 4).
  - 2. Read and write state machines can be active simultaneously. Read and write cannot be simultaneously initiated. Read takes precedence.
  - 3. State machine control timing sequence is controlled by K.

#### **Electrical Characteristics**

### **Absolute Maximum Ratings**

Parameter	Symbol	Rating	Unit	Notes
Input voltage on any ball	V <sub>IN</sub>	–0.5 to V <sub>DD</sub> + 0.5 (2.5 V max.)	V	1,4
Input/output voltage	V <sub>I/O</sub>	-0.5 to V <sub>DDQ</sub> + 0.5 (2.5 V max.)	V	1,4
Core supply voltage	$V_{DD}$	-0.5 to 2.5	V	1,4
Output supply voltage	$V_{DDQ}$	-0.5 to V <sub>DD</sub>	V	1,4
Junction temperature	Tj	+125 (max)	°C	5
Storage temperature	T <sub>STG</sub>	-55 to +125	°C	

#### Notes:

- 1. All voltage is referenced to  $V_{SS}$ .
- 2. Permanent device damage may occur if Absolute Maximum Ratings are exceeded. Functional operation should be restricted the Operation Conditions. Exposure to higher than recommended voltages for extended periods of time could affect device reliability.
- 3. These CMOS memory circuits have been designed to meet the DC and AC specifications shown in the tables after thermal equilibrium has been established.
- 4. The following supply voltage application sequence is recommended:  $V_{SS}$ ,  $V_{DD}$ ,  $V_{DDQ}$ ,  $V_{REF}$  then  $V_{IN}$ . Remember, according to the Absolute Maximum Ratings table,  $V_{DDQ}$  is not to exceed 2.5 V, whatever the instantaneous value of  $V_{DDQ}$ .
- 5. Some method of cooling or airflow should be considered in the system.

#### **Recommended DC Operating Conditions**

Parameter	Symbol	Min	Тур	Max	Unit	Notes
Power supply voltage core	$V_{DD}$	1.7	1.8	1.9	V	1
Power supply voltage I/O	$V_{DDQ}$	1.4	1.5	$V_{DD}$	V	1,2
Input reference voltage I/O	$V_{REF}$	0.68	0.75	0.95	V	3
Input high voltage	V <sub>IH (DC)</sub>	V <sub>REF</sub> + 0.1	-	V <sub>DDQ</sub> + 0.3	V	1,4,5
Input low voltage	V <sub>IL (DC)</sub>	-0.3	-	V <sub>REF</sub> - 0.1	V	1,4,5

#### Notes:

- 1. At power-up,  $V_{DD}$  and  $V_{DDQ}$  are assumed to be a linear ramp from 0V to  $V_{DD}$ (min.) or  $V_{DDQ}$ (min.) within 200ms. During this time  $V_{DDQ} < V_{DD}$  and  $V_{IH} < V_{DDQ}$ . During normal operation,  $V_{DDQ}$  must not exceed  $V_{DD}$ .
- 2. Please pay attention to Tj not to exceed the temperature shown in the absolute maximum ratings table due to current from  $V_{DDO}$ .
- 3. Peak to peak AC component superimposed on  $V_{REF}$  may not exceed 5% of  $V_{REF}$ .
- 4. These are DC test criteria. The AC  $V_{IH}$  /  $V_{IL}$  levels are defined separately to measure timing parameters.
- 5. Overshoot:  $V_{IH (AC)} \le V_{DDQ} + 0.5 \text{ V for } t \le t_{KHKH}/2$

Undershoot:  $V_{\text{IL (AC)}} \ge -0.5 \text{ V for } t \le t_{\text{KHKH/}}2$ 

During normal operation,  $V_{IH(DC)}$  must not exceed  $V_{DDQ}$  and  $V_{IL(DC)}$  must not be lower than  $V_{SS}$ .

### **DC Characteristics**

$$(T_A = -40 \text{ to } +85^{\circ}\text{C}, V_{DD} = 1.8\text{V} \pm 0.1\text{V}, V_{DDQ} = 1.5\text{V}, V_{REF} = 0.75\text{V})$$

Parameter	Symbol	Test condition	MIN.	MAX. -25	Unit	Notes
Operating Supply	I <sub>DD</sub>	(x36)		1170	mA	
Current		(x18)		980		1,2,3
(Write / Read)						
Standby Supply	I <sub>SB1</sub>	(x36)		920	mA	
Current		(x18)		780		2,4,5
(NOP)						
Input leakage current	lu		-2	2	μА	9
Output leakage current	I <sub>LO</sub>		-5	5	μΑ	10
Output high voltage	V <sub>OH</sub> (Low)	I <sub>OH</sub>   ≤ 0.1 mA	V <sub>DDQ</sub> - 0.2	V <sub>DDQ</sub>	V	8
	V <sub>OH</sub>	Note 6	$V_{DDQ}/2-0.12$	V <sub>DDQ</sub> /2 + 0.12	V	8
Output low voltage	V <sub>OL</sub> (Low)	$I_{OL} \le 0.1 \text{ mA}$	Vss	0.2	V	8
	V <sub>OL</sub>	Note 7	V <sub>DDQ</sub> /2- 0.12	V <sub>DDQ</sub> /2+ 0.12	V	8

- 1. All inputs (except ZQ,  $V_{\text{REF}}$ ) are held at either  $V_{\text{IH}}$  or  $V_{\text{IL}}$ .
- 2.  $I_{OUT} = 0$  mA.  $V_{DD} = V_{DD}$  max,  $t_{KHKH} = t_{KHKH}$  min.
- 3. Operating supply currents ( $I_{DD}$ ) are measured at 100% bus utilization.  $I_{DD}$  of QDR family is current of device with 100% write and 100% read cycle.
- 4. All address / data inputs are static at either  $V_{IN} > V_{IH}$  or  $V_{IN} < V_{IL}$ .
- 5. Reference value. (Condition = NOP currents are valid when entering NOP after all pending READ and WRITE cycles are completed.)
- 6. Outputs are impedance-controlled.  $|I_{OH}| = (V_{DDQ}/2)/(RQ/5)$  for values of 175  $\Omega \le RQ \le 350 \Omega$ .
- 7. Outputs are impedance-controlled.  $I_{OL} = (V_{DDQ}/2)/(RQ/5)$  for values of 175  $\Omega \le RQ \le 350 \Omega$ .
- 8. AC load current is higher than the shown DC values. AC I/O curves are available upon request.
- 9.  $0 \le V_{IN} \le V_{DDQ}$  for all input balls (except  $V_{REF}$ , Dn, /BWx, K, /K, ZQ, ODT, TCK, TMS, TDI ball).
- 10.  $0 \le V_{OUT} \le V_{DDO}$  (except TDO ball), output disabled.

#### **Thermal Resistance**

Parameter	Symbol	Airflow	Тур	Unit	Test condition	Notes
Junction to Ambient	$\theta_{JA}$	1 m/s	9.7	°C/W	EIA/JEDEC JESD51	1
Junction to Case	$\theta_{JC}$	-	4.4			

Notes:

1. These parameters are calculated under the condition. These are reference values.

2.  $Tj = Ta + \theta_{JA} \times Pd$ 

 $Tj = Tc + \theta_{JC} \times Pd$ 

where

Tj: junction temperature when the device has achieved a steady-state after application of Pd (°C)

Ta :ambient temperature (°C)

Tc: temperature of external surface of the package or case (°C)

 $\theta_{JA}$ : thermal resistance from junction-to-ambient (°C/W)

 $\theta_{JC}$ : thermal resistance from junction-to-case (package) (°C/W)

Pd:power dissipation that produced change in junction temperature (W) (cf.JESD51-2A)

#### Capacitance

$$(Ta = +25^{\circ}C, Frequency = 1.0MHz, V_{DD} = 1.8V, V_{DDO} = 1.5V)$$

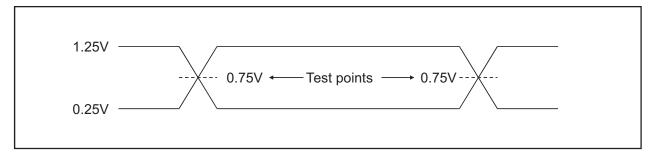
Parameter	Symbol	Min	Тур	Max	Unit	Test condition	Note
Input capacitance (SA, /R, /W, /BW)	C <sub>IN</sub>	-	4	5	pF	V <sub>IN</sub> = 0 V	1,2
Clock input capacitance (K, /K)	C <sub>CLK</sub>	-	4	5	pF	V <sub>CLK</sub> = 0 V	1,2
Output capacitance (DQ, CQ, /CQ)	C <sub>I/O</sub>	-	5	6	pF	V <sub>I/O</sub> = 0 V	1,2

Notes:

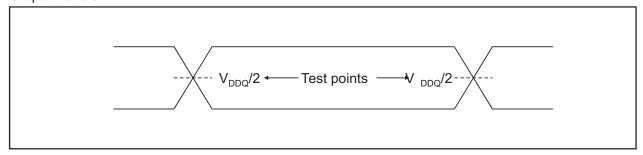
- 1. These parameters are sampled and not 100% tested.
- 2. Except JTAG (TCK, TMS, TDI, TDO) pins.

### **AC Test Conditions**

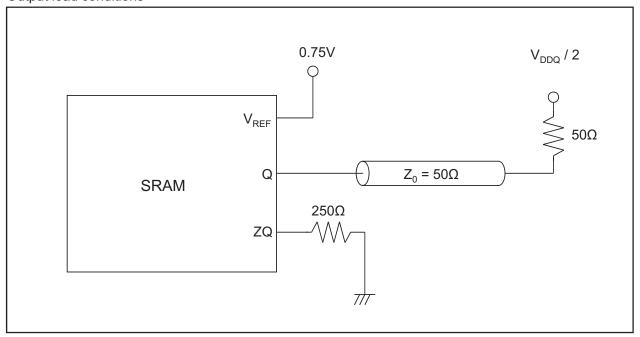
Input waveform (Rise/fall time ≤ 0.3 ns)



#### Output waveform



#### Output load conditions



#### **AC Operating Conditions**

Parameter	Symbol	Min	Тур	Max	Unit	Notes
Input high voltage	V <sub>IH (AC)</sub>	V <sub>REF</sub> + 0.2	-	-	V	1,2,3,4
Input low voltage	V <sub>IL (AC)</sub>	-	-	V <sub>REF</sub> – 0.2	V	1,2,3,4

#### Notes:

- 1. All voltages referenced to V<sub>SS</sub> (GND). During normal operation, V<sub>DDO</sub> must not exceed V<sub>DD</sub>.
- 2. These conditions are for AC functions only, not for AC parameter test.
- 3. Overshoot:  $V_{IH (AC)} \le V_{DDQ} + 0.5 \text{ V for } t \le t_{KHKH}/2$

Undershoot:  $V_{\text{IL (AC)}} \ge -0.5 \text{ V for } t \le t_{\text{KHKH}}/2$ 

Control input signals may not have pulse widths less than  $t_{KHKL}$  (min) or operate at cycle rates less than  $t_{KHKH}$  (min).

- 4. To maintain a valid level, the transitioning edge of the input must:
  - a. Sustain a constant slew rate from the current AC level through the target AC level,  $V_{\rm IL\ (AC)}$  or  $V_{\rm IH\ (AC)}$ .
  - b. Reach at least the target AC level.
  - c. After the AC target level is reached, continue to maintain at least the target DC level,  $V_{\rm IL\,(DC)}$  or  $V_{\rm IH\,(DC)}$ .

# **AC Characteristics**

 $(T_A = -40 \text{ to } +85^{\circ}\text{C}, V_{DD} = 1.8\text{V} \pm 0.1\text{V}, V_{DDQ} = 1.5\text{V}, V_{REF} = 0.75\text{V})$ 

Parameter	Symbol	-25		Unit	Notes
		Min	Max		
Clock					
Average clock cycle time (K, /K)	t <sub>кнкн</sub>	2.50	4.00	ns	
Clock high time (K, /K)	t <sub>KHKL</sub>	0.40	-	Cycle	
Clock low time (K, /K)	t <sub>KLKH</sub>	0.40	-	Cycle	
Clock to /clock (K to /K)	t <sub>кн/кн</sub>	0.425	-	Cycle	
/Clock to clock (/K to K)	t <sub>/KHKH</sub>	0.425	-	Cycle	
PLL Timing					
Clock phase jitter (K, /K)	t <sub>KC</sub> var	-	0.20	ns	3
Lock time (K)	t <sub>KC</sub> lock	20	-	us	2
K static to PLL reset	t <sub>KC</sub> reset	30	-	ns	5
Output Times					
K, /K high to output valid	t <sub>CHQV</sub>	-	0.45	ns	
K, /K high to output hold	t <sub>CHQX</sub>	-0.45	-	ns	
K, /K high to echo clock valid	t <sub>CHCQV</sub>	-	0.45	ns	
K, /K high to echo clock hold	t <sub>CHCQX</sub>	-0.45	-	ns	
CQ, /CQ high to output valid	t <sub>CQHQV</sub>	-	0.20	ns	5
CQ, /CQ high to output hold	t <sub>CQHQX</sub>	-0.20	-	ns	5
K, /K high to output high-Z	t <sub>CHQZ</sub>	-	0.45	ns	4
K, /K high to output low-Z	t <sub>CHQX1</sub>	-0.45	-	ns	4
CQ high to QVLD valid	t <sub>QVLD</sub>	-0.20	0.20	ns	5
Setup Times					
Address valid to K rising edge	t <sub>AVKH</sub>	0.40	-	ns	1
Control inputs valid to K rising edge	t <sub>IVKH</sub>	0.40	-	ns	1
Data-in valid to K, /K rising edge	t <sub>DVKH</sub>	0.28	-	ns	1
Hold Times					
K rising edge to address hold	t <sub>KHAX</sub>	0.40	-	ns	1
K rising edge to control inputs hold	t <sub>KHIX</sub>	0.40	-	ns	1
K, /K rising edge to data-in hold	t <sub>KHDX</sub>	0.28	-	ns	1

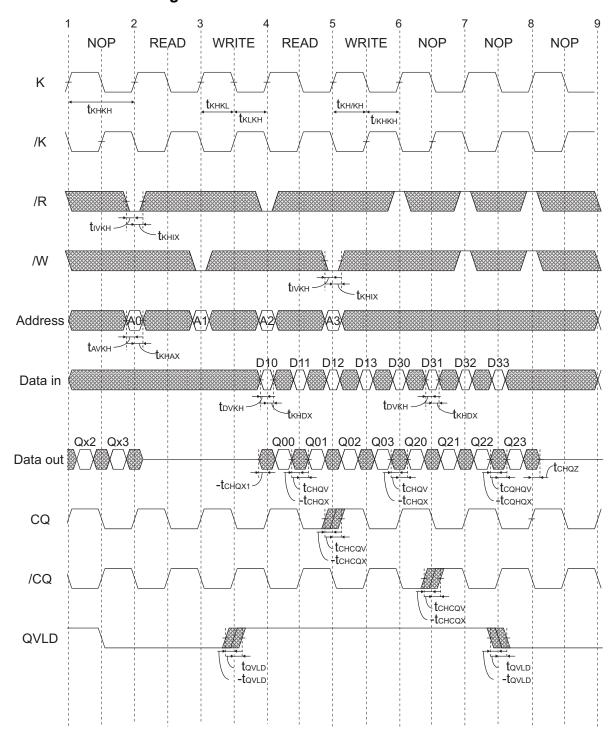
#### Notes:

- 1. This is a synchronous device. All addresses, data and control lines must meet the specified setup and hold times for all latching clock edges.
- 2.  $V_{DD}$  and  $V_{DDQ}$  slew rate must be less than 0.1 V DC per 50 ns for PLL lock retention. PLL lock time begins once  $V_{DD}$ ,  $V_{DDQ}$  and input clock are stable. It is recommended that the device is kept inactive during these cycles.
- 3. Clock phase jitter is the variance from clock rising edge to the next expected clock rising edge.
- 4. Transitions are measured  $\pm 100$  mV from steady-state voltage.
- 5. These parameters are sampled.

#### Remarks:

- 1. Test conditions as specified with the output loading as shown in AC Test Conditions unless otherwise noted.
- 2. Control input signals may not be operated with pulse widths less than  $t_{KHKL}$  (min).
- 3.  $V_{DDO}$  is +1.5 V DC.  $V_{REF}$  is +0.75 V DC.
- 4. Control signals are /R and /W.
  - Setup and hold times of /BWx signals must be the same as those of Data-in signals.

# **Read and Write Timing**



- 1. Q00 refers to output from address A0+0. Q01 refers to output from the next internal burst address following A0, i.e., A0+1.
- 2. In this example, if address A2 = A1, then data Q20 = D10, Q21 = D11, Q22 = D12, Q23 = D13. Write data is forwarded immediately as read results.
- 3. To control read and write operations, /BW signals must operate at the same timing as Data-in signals.

# **JTAG Specification**

These products support a limited set of JTAG functions as in IEEE standard 1149.1.

#### **Disabling the Test Access Port**

It is possible to use this device without utilizing the TAP. To disable the TAP controller without interfering with normal operation of the device, TCK must be tied to  $V_{SS}$  to preclude middle level inputs. TDI and TMS are internally pulled up and may be unconnected, or may be connected to  $V_{DD}$  through a pull up resistor. TDO should be left unconnected.

#### **Test Access Port (TAP) Pins**

Symbol I/O	Pin assignments	Description	Notes
TCK	2R	Test clock input. All inputs are captured on the rising edge of TCK and all outputs propagate from the falling edge of TCK.	
TMS	10R	Test mode select. This is the command input for the TAP controller state machine.	
TDI	11R	Test data input. This is the input side of the serial registers placed between TDI and TDO. The register placed between TDI and TDO is determined by the state of the TAP controller state machine and the instruction that is currently loaded in the TAP instruction.	
TDO	1R	Test data output. Output changes in response to the falling edge of TCK. This is the output side of the serial registers placed between TDI and TDO.	

Notes:

The device does not have TRST (TAP reset). The Test-Logic Reset state is entered while TMS is held high for five rising edges of TCK. The TAP controller state is also reset on SRAM POWER-UP.

#### **TAP DC Operating Characteristics**

$$(T_A = -40 \text{ to } +85^{\circ}\text{C}, V_{DD} = 1.8\text{V} \pm 0.1\text{V})$$

Parameter	Symbol	Min	Тур	Max	Unit	Notes
Input high voltage	$V_{IH}$	+1.3	-	$V_{DD} + 0.3$	V	
Input low voltage	$V_{IL}$	-0.3	-	+0.5	V	
Input leakage current	ILI	-5.0	-	+5.0	μΑ	$0 \text{ V} \leq V_{IN} \leq V_{DD}$
Output leakage current	I <sub>LO</sub>	-5.0	-	+5.0	μΑ	$0 \text{ V} \leq V_{IN} \leq V_{DD}$ , output disabled
Output low voltage	$V_{OL1}$	-	-	0.2	٧	$I_{OLC}$ = 100 $\mu$ A
Output low voltage	$V_{OL2}$	-	-	0.4	V	$I_{OLT} = 2 \text{ mA}$
Output high voltage	V <sub>OH1</sub>	1.6	-	-	V	$ I_{OHC}  = 100 \mu A$
Output high voltage	$V_{\mathrm{OH2}}$	1.4	-	-	V	I <sub>OHT</sub>   = 2 mA

Notes:

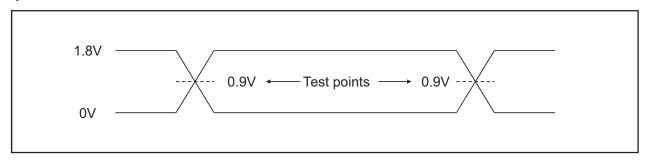
- 1. All voltages referenced to  $V_{SS}$  (GND).
- 2. At power-up,  $V_{DD}$  and  $V_{DDQ}$  are assumed to be a linear ramp from 0V to  $V_{DD}$ (min.) or  $V_{DDQ}$ (min.) within 200ms. During this time,  $V_{DDQ} < V_{DD}$  and  $V_{IH} < V_{DDQ}$ .

During normal operation,  $V_{\text{DDQ}}$  must not exceed  $V_{\text{DD}}$ .

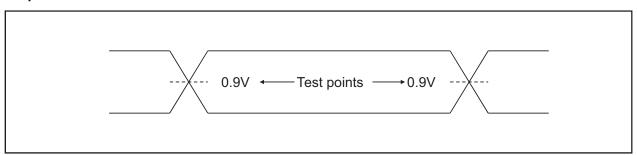
# **TAP AC Test Conditions**

Parameter	Symbol	Conditions	Unit	Notes
Input timing measurement reference levels	$V_{REF}$	0.9	V	
Input pulse levels	$V_{IL}, V_{IH}$	0 to 1.8	V	
Input rise/fall time	tr, tf	≤ 1.0	ns	
Output timing measurement reference levels		0.9	V	
Test load termination supply voltage (V <sub>TT</sub> )		0.9	V	
Output load		See figures		

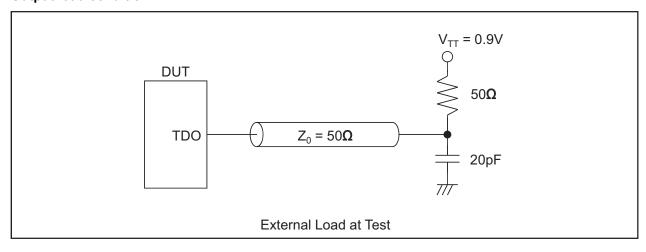
#### Input waveform



# **Output waveform**



# **Output load condition**



# **TAP AC Operating Characteristics**

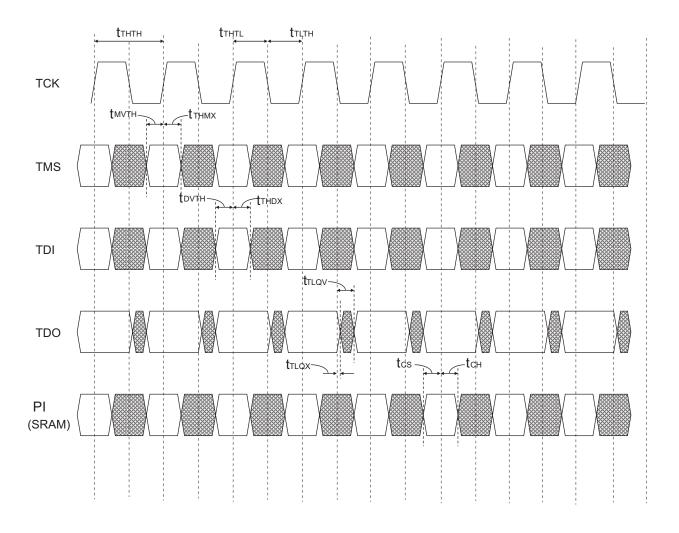
(  $T_A$  = -40 to +85°C,  $V_{DD}$  = 1.8V ± 0.1V )

Parameter	Symbol	Min	Тур	Max	Unit	Notes
Test clock (TCK) cycle time	t <sub>THTH</sub>	50	-	-	ns	
TCK high pulse width	t <sub>THTL</sub>	20	-	-	ns	
TCK low pulse width	t <sub>TLTH</sub>	20	-	-	ns	
Test mode select (TMS) setup	t <sub>MVTH</sub>	5	-	-	ns	
TMS hold	t <sub>THMX</sub>	5	-	-	ns	
Capture setup	t <sub>CS</sub>	5	-	-	ns	
Capture hold	t <sub>CH</sub>	5	-	-	ns	
TDI valid to TCK high	t <sub>DVTH</sub>	5	-	-	ns	
TCK high to TDI invalid	t <sub>THDX</sub>	5	-	-	ns	
TCK low to TDO unknown	t <sub>TLQX</sub>	0	-	-	ns	
TCK low to TDO valid	t <sub>TLQV</sub>	-	-	10	ns	

Notes:

1.  $t_{CS} + t_{CH}$  defines the minimum pause in RAM I/O pad transitions to assure pad data capture.

# **TAP Controller Timing Diagram**



# **Test Access Port Registers**

Register name	Length	Symbol	Notes
Instruction register	3 bits	IR [2:0]	
Bypass register	1 bits	BP	
ID register	32 bits	ID [31:0]	
Boundary scan register	109 bit	BS [109:1]	

#### **TAP Controller Instruction Set**

IR2	IR1	IR0	Instruction	Description	Notes
0	0	0	EXTEST	The EXTEST instruction allows circuitry external to the component package to be tested. Boundary scan register cells at output balls are used to apply test vectors, while those at input balls capture test results. Typically, the first test vector to be applied using the EXTEST instruction will be shifted into the boundary scan register using the PRELOAD instruction. Thus, during the Update-IR state of EXTEST, the output driver is turned on and the PRELOAD data is driven onto the output balls.	1,2,3,4,5
0	0	1	IDCODE	The IDCODE instruction causes the ID ROM to be loaded into the ID register when the controller is in capture-DR mode and places the ID register between the TDI and TDO balls in shift-DR mode. The IDCODE instruction is the default instruction loaded in at power up and any time the controller is placed in the Test-Logic-Reset state.	
0	1	0	SAMPLE-Z	If the SAMPLE-Z instruction is loaded in the instruction register, all RAM outputs are forced to an inactive drive state (high-Z), moving the TAP controller into the capture-DR state loads the data in the RAMs input into the boundary scan register, and the boundary scan register is connected between TDI and TDO when the TAP controller is moved to the shift-DR state.	3,4,5
0	1	1	RESERVED	The RESERVED instruction is not implemented but is reserved for future use. Do not use this instruction.	
1	0	0	SAMPLE (/PRELOAD)	When the SAMPLE instruction is loaded in the instruction register, moving the TAP controller into the capture-DR state loads the data in the RAMs input and I/O buffers into the boundary scan register. Because the RAM clock(s) are independent from the TAP clock (TCK) it is possible for the TAP to attempt to capture the I/O ring contents while the input buffers are in transition (i.e., in a metastable state). Although allowing the TAP to SAMPLE metastable input will not harm the device, repeatable results cannot be expected. Moving the controller to shift-DR state then places the boundary scan register between the TDI and TDO balls.	3,4,5
1	0	1	RESERVED	The RESERVED instruction is not implemented but is reserved for future use. Do not use this instruction.	
1	1	0	RESERVED	The RESERVED instruction is not implemented but is reserved for future use. Do not use this instruction.	
1	1	1	BYPASS	The BYPASS instruction is loaded in the instruction register when the bypass register is placed between TDI and TDO. This occurs when the TAP controller is moved to the shift-DR state. This allows the board level scan path to be shortened to facilitate testing of other devices in the scan path.	

- 1. Data in output register is not guaranteed if EXTEST instruction is loaded.
- 2. After performing EXTEST, power-up conditions are required in order to return part to normal operation.
- 3. RAM input signals must be stabilized for long enough to meet the TAPs input data capture setup plus hold time (t<sub>CS</sub> plus t<sub>CH</sub>). The RAMs clock inputs need not be paused for any other TAP operation except capturing the I/O ring contents into the boundary scan register.
- 4. Clock recovery initialization cycles are required after boundary scan.
- 5. ODT is disabled in EXTEST, SAMPLE-Z or SAMPLE mode.

# **Boundary Scan Order**

Bit#	Ball		
Bitar	ID	x18	x36
1	6R	ODT	ODT
2	6P	QVLD	QVLD
3	6N	SA	SA
4	7P	SA	SA
5	7N	SA	SA
6	7R	SA	SA
7	8R	SA	SA
8	8P	SA	SA
9	9R	SA	SA
10	11P	Q0	Q0
11	10P	D0	D0
12	10N	NC	D9
13	9P	NC	Q9
14	10M	Q1	Q1
15	11N	D1	D1
16	9M	NC	D10
17	9N	NC	Q10
18	11L	Q2	Q2
19	11M	D2	D2
20	9L	NC	D11
21	10L	NC	Q11
22	11K	Q3	Q3
23	10K	D3	D3
24	9J	NC	D12
25	9K	NC	Q12
26	10J	Q4	Q4
27	11J	D4	D4
28	11H	ZQ	ZQ
29	10G	NC	D13
30	9G	NC	Q13
31	11F	Q5	Q5
32	11G	D5	D5
33	9F	NC	D14
34	10F	NC	Q14
35	11E	Q6	Q6
36	10E	D6	D6
37	10D	NC	D15

Bit#	Ball	Signal names	
<b>D</b> ia	ID	x18	x36
38	9E	NC	Q15
39	10C	Q7	Q7
40	11D	D7	D7
41	9C	NC	D16
42	9D	NC	Q16
43	11B	Q8	Q8
44	11C	D8	D8
45	9B	NC	D17
46	10B	NC	Q17
47	11A	CQ	Q
48	10A	SA	SA
49	9A	SA	SA
50	8B	SA	SA
51	7C	SA	SA
52	6C	NC	NC
53	8A	/R	/R
54	7A	NC	/BW1
55	7B	/BW0	/BW0
56	6B	K	K
57	6A	/K	/K
58	5B	NC	/BW3
59	5A	/BW1	/BW2
60	4A	/W	/W
61	5C	SA	SA
62	4B	SA	SA
63	3A	SA	SA
64	2A	SA	NC
65	1A	/CQ	/CQ
66	2B	Q9	Q18
67	3B	D9	D18
68	1C	NC	D27
69	1B	NC	Q27
70	3D	Q10	Q19
71	3C	D10	D19
72	1D	NC	D28
73	2C	NC	Q28
74	3E	Q11	Q20
	<u> </u>		

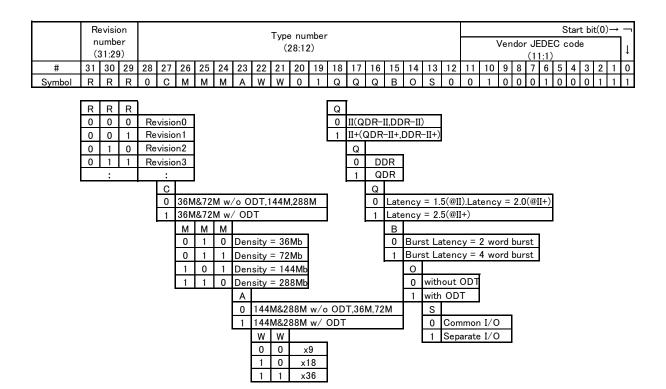
Bit#         Ball ID         Signal names           75         2D         D11         D20           76         2E         NC         D29           77         1E         NC         Q29           78         2F         Q12         Q21           79         3F         D12         D21           80         1G         NC         D30           81         1F         NC         Q30           82         3G         Q13         Q22           83         2G         D13         D22           84         1H         /DOFF         /DOFF           85         1J         NC         D31           86         2J         NC         Q31           87         3K         Q14         Q23           88         3J         D14         D23           89         2K         NC         D32           90         1K         NC         Q32           91         2L         Q15         Q24           92         3L         D15         D24           93         1M         NC         Q33           94					
N	Rit#	Ball	Signal names		
76         2E         NC         D29           77         1E         NC         Q29           78         2F         Q12         Q21           79         3F         D12         D21           80         1G         NC         D30           81         1F         NC         Q30           82         3G         Q13         Q22           83         2G         D13         D22           84         1H         //DOFF         /DOFF           85         1J         NC         D31           86         2J         NC         Q31           87         3K         Q14         Q23           88         3J         D14         D23           89         2K         NC         D32           90         1K         NC         Q32           91         2L         Q15         Q24           92         3L         D15         D24           93         1M         NC         D33           94         1L         NC         Q33           95         3N         Q16         Q25           96	Dit.	ID	x18	x36	
77         1E         NC         Q29           78         2F         Q12         Q21           79         3F         D12         D21           80         1G         NC         D30           81         1F         NC         Q30           82         3G         Q13         Q22           83         2G         D13         D22           84         1H         /DOFF         /DOFF           85         1J         NC         D31           86         2J         NC         Q31           87         3K         Q14         Q23           88         3J         D14         D23           89         2K         NC         D32           90         1K         NC         Q32           91         2L         Q15         Q24           92         3L         D15         D24           93         1M         NC         D33           94         1L         NC         Q33           95         3N         Q16         Q25           96         3M         D16         D25           97					
78         2F         Q12         Q21           79         3F         D12         D21           80         1G         NC         D30           81         1F         NC         Q30           82         3G         Q13         Q22           83         2G         D13         D22           84         1H         /DOFF         /DOFF           85         1J         NC         D31           86         2J         NC         Q31           87         3K         Q14         Q23           88         3J         D14         D23           89         2K         NC         D32           90         1K         NC         Q32           91         2L         Q15         Q24           92         3L         D15         D24           93         1M         NC         D33           94         1L         NC         Q33           95         3N         Q16         Q25           96         3M         D16         D25           97         1N         NC         D34           98					
79         3F         D12         D21           80         1G         NC         D30           81         1F         NC         Q30           82         3G         Q13         Q22           83         2G         D13         D22           84         1H         /DOFF         /DOFF           85         1J         NC         D31           86         2J         NC         Q31           87         3K         Q14         Q23           88         3J         D14         D23           89         2K         NC         D32           90         1K         NC         Q32           91         2L         Q15         Q24           92         3L         D15         D24           93         1M         NC         D33           94         1L         NC         Q33           95         3N         Q16         Q25           96         3M         D16         D25           97         1N         NC         D34           98         2M         NC         D34           98	77	1E	NC	Q29	
80         1G         NC         D30           81         1F         NC         Q30           82         3G         Q13         Q22           83         2G         D13         D22           84         1H         /DOFF         /DOFF           85         1J         NC         D31           86         2J         NC         Q31           87         3K         Q14         Q23           88         3J         D14         D23           89         2K         NC         D32           90         1K         NC         Q32           91         2L         Q15         Q24           92         3L         D15         D24           93         1M         NC         D33           94         1L         NC         Q33           95         3N         Q16         Q25           96         3M         D16         D25           97         1N         NC         D34           98         2M         NC         Q34           99         3P         Q17         Q26           100		2F			
81         1F         NC         Q30           82         3G         Q13         Q22           83         2G         D13         D22           84         1H         /DOFF         /DOFF           85         1J         NC         D31           86         2J         NC         Q31           87         3K         Q14         Q23           88         3J         D14         D23           89         2K         NC         D32           90         1K         NC         Q32           91         2L         Q15         Q24           92         3L         D15         D24           93         1M         NC         D33           94         1L         NC         Q33           95         3N         Q16         Q25           96         3M         D16         D25           97         1N         NC         D34           98         2M         NC         Q34           99         3P         Q17         Q26           100         2N         D17         D26           100 <td>79</td> <td>3F</td> <td>D12</td> <td></td>	79	3F	D12		
82         3G         Q13         Q22           83         2G         D13         D22           84         1H         /DOFF         /DOFF           85         1J         NC         D31           86         2J         NC         Q31           87         3K         Q14         Q23           88         3J         D14         D23           89         2K         NC         D32           90         1K         NC         Q32           91         2L         Q15         Q24           92         3L         D15         D24           93         1M         NC         D33           94         1L         NC         Q33           95         3N         Q16         Q25           96         3M         D16         D25           97         1N         NC         D34           98         2M         NC         Q34           99         3P         Q17         Q26           100         2N         D17         D26           101         2P         NC         D35           102 <td>80</td> <td>1G</td> <td>NC</td> <td>D30</td>	80	1G	NC	D30	
83         2G         D13         D22           84         1H         /DOFF         /DOFF           85         1J         NC         D31           86         2J         NC         Q31           87         3K         Q14         Q23           88         3J         D14         D23           89         2K         NC         D32           90         1K         NC         Q32           91         2L         Q15         Q24           92         3L         D15         D24           93         1M         NC         D33           94         1L         NC         Q33           95         3N         Q16         Q25           96         3M         D16         D25           97         1N         NC         D34           98         2M         NC         Q34           99         3P         Q17         Q26           100         2N         D17         D26           101         2P         NC         D35           102         1P         NC         Q35           103 <td>81</td> <td>1F</td> <td>NC</td> <td>Q30</td>	81	1F	NC	Q30	
84         1H         /DOFF         /DOFF           85         1J         NC         D31           86         2J         NC         Q31           87         3K         Q14         Q23           88         3J         D14         D23           89         2K         NC         D32           90         1K         NC         Q32           91         2L         Q15         Q24           92         3L         D15         D24           93         1M         NC         D33           94         1L         NC         Q33           95         3N         Q16         Q25           96         3M         D16         D25           97         1N         NC         D34           98         2M         NC         Q34           99         3P         Q17         Q26           100         2N         D17         D26           101         2P         NC         D35           102         1P         NC         Q35           103         3R         SA         SA           104 <td>82</td> <td>3G</td> <td>Q13</td> <td>Q22</td>	82	3G	Q13	Q22	
85         1J         NC         D31           86         2J         NC         Q31           87         3K         Q14         Q23           88         3J         D14         D23           89         2K         NC         D32           90         1K         NC         Q32           91         2L         Q15         Q24           92         3L         D15         D24           93         1M         NC         D33           94         1L         NC         Q33           95         3N         Q16         Q25           96         3M         D16         D25           97         1N         NC         D34           98         2M         NC         Q34           99         3P         Q17         Q26           100         2N         D17         D26           101         2P         NC         D35           102         1P         NC         Q35           103         3R         SA         SA           104         4R         SA         SA           105	83	2G		D22	
86         2J         NC         Q31           87         3K         Q14         Q23           88         3J         D14         D23           89         2K         NC         D32           90         1K         NC         Q32           91         2L         Q15         Q24           92         3L         D15         D24           93         1M         NC         D33           94         1L         NC         Q33           95         3N         Q16         Q25           96         3M         D16         D25           97         1N         NC         D34           98         2M         NC         Q34           99         3P         Q17         Q26           100         2N         D17         D26           101         2P         NC         D35           102         1P         NC         Q35           103         3R         SA         SA           104         4R         SA         SA           105         4P         SA         SA           106	84	1H	/DOFF	/DOFF	
87         3K         Q14         Q23           88         3J         D14         D23           89         2K         NC         D32           90         1K         NC         Q32           91         2L         Q15         Q24           92         3L         D15         D24           93         1M         NC         D33           94         1L         NC         Q33           95         3N         Q16         Q25           96         3M         D16         D25           97         1N         NC         D34           98         2M         NC         Q34           99         3P         Q17         Q26           100         2N         D17         D26           101         2P         NC         D35           102         1P         NC         Q35           103         3R         SA         SA           104         4R         SA         SA           105         4P         SA         SA           106         5P         SA         SA           106	85		NC	D31	
88         3J         D14         D23           89         2K         NC         D32           90         1K         NC         Q32           91         2L         Q15         Q24           92         3L         D15         D24           93         1M         NC         D33           94         1L         NC         Q33           95         3N         Q16         Q25           96         3M         D16         D25           97         1N         NC         D34           98         2M         NC         Q34           99         3P         Q17         Q26           100         2N         D17         D26           101         2P         NC         D35           102         1P         NC         Q35           103         3R         SA         SA           104         4R         SA         SA           105         4P         SA         SA           106         5P         SA         SA           107         5N         SA         SA           108	86	2J		Q31	
89         2K         NC         D32           90         1K         NC         Q32           91         2L         Q15         Q24           92         3L         D15         D24           93         1M         NC         D33           94         1L         NC         Q33           95         3N         Q16         Q25           96         3M         D16         D25           97         1N         NC         D34           98         2M         NC         Q34           99         3P         Q17         Q26           100         2N         D17         D26           101         2P         NC         D35           102         1P         NC         Q35           103         3R         SA         SA           104         4R         SA         SA           105         4P         SA         SA           106         5P         SA         SA           107         5N         SA         SA           108         5R         SA         SA	87	3K	Q14	Q23	
90         1K         NC         Q32           91         2L         Q15         Q24           92         3L         D15         D24           93         1M         NC         D33           94         1L         NC         Q33           95         3N         Q16         Q25           96         3M         D16         D25           97         1N         NC         D34           98         2M         NC         Q34           99         3P         Q17         Q26           100         2N         D17         D26           101         2P         NC         D35           102         1P         NC         Q35           103         3R         SA         SA           104         4R         SA         SA           105         4P         SA         SA           106         5P         SA         SA           107         5N         SA         SA           108         5R         SA         SA	88	3J	D14	D23	
91         2L         Q15         Q24           92         3L         D15         D24           93         1M         NC         D33           94         1L         NC         Q33           95         3N         Q16         Q25           96         3M         D16         D25           97         1N         NC         D34           98         2M         NC         Q34           99         3P         Q17         Q26           100         2N         D17         D26           101         2P         NC         D35           102         1P         NC         Q35           103         3R         SA         SA           104         4R         SA         SA           105         4P         SA         SA           106         5P         SA         SA           108         5R         SA         SA	89	2K	NC	D32	
92         3L         D15         D24           93         1M         NC         D33           94         1L         NC         Q33           95         3N         Q16         Q25           96         3M         D16         D25           97         1N         NC         D34           98         2M         NC         Q34           99         3P         Q17         Q26           100         2N         D17         D26           101         2P         NC         D35           102         1P         NC         Q35           103         3R         SA         SA           104         4R         SA         SA           105         4P         SA         SA           106         5P         SA         SA           107         5N         SA         SA           108         5R         SA         SA	90	1K	NC	Q32	
93         1M         NC         D33           94         1L         NC         Q33           95         3N         Q16         Q25           96         3M         D16         D25           97         1N         NC         D34           98         2M         NC         Q34           99         3P         Q17         Q26           100         2N         D17         D26           101         2P         NC         D35           102         1P         NC         Q35           103         3R         SA         SA           104         4R         SA         SA           105         4P         SA         SA           106         5P         SA         SA           107         5N         SA         SA           108         5R         SA         SA	91	2L	Q15	Q24	
94         1L         NC         Q33           95         3N         Q16         Q25           96         3M         D16         D25           97         1N         NC         D34           98         2M         NC         Q34           99         3P         Q17         Q26           100         2N         D17         D26           101         2P         NC         D35           102         1P         NC         Q35           103         3R         SA         SA           104         4R         SA         SA           105         4P         SA         SA           106         5P         SA         SA           107         5N         SA         SA           108         5R         SA         SA	92	3L	D15	D24	
95         3N         Q16         Q25           96         3M         D16         D25           97         1N         NC         D34           98         2M         NC         Q34           99         3P         Q17         Q26           100         2N         D17         D26           101         2P         NC         D35           102         1P         NC         Q35           103         3R         SA         SA           104         4R         SA         SA           105         4P         SA         SA           106         5P         SA         SA           107         5N         SA         SA           108         5R         SA         SA	93	1M	NC	D33	
96         3M         D16         D25           97         1N         NC         D34           98         2M         NC         Q34           99         3P         Q17         Q26           100         2N         D17         D26           101         2P         NC         D35           102         1P         NC         Q35           103         3R         SA         SA           104         4R         SA         SA           105         4P         SA         SA           106         5P         SA         SA           107         5N         SA         SA           108         5R         SA         SA	94	1L	NC	Q33	
97         1N         NC         D34           98         2M         NC         Q34           99         3P         Q17         Q26           100         2N         D17         D26           101         2P         NC         D35           102         1P         NC         Q35           103         3R         SA         SA           104         4R         SA         SA           105         4P         SA         SA           106         5P         SA         SA           107         5N         SA         SA           108         5R         SA         SA	95	3N	Q16	Q25	
98         2M         NC         Q34           99         3P         Q17         Q26           100         2N         D17         D26           101         2P         NC         D35           102         1P         NC         Q35           103         3R         SA         SA           104         4R         SA         SA           105         4P         SA         SA           106         5P         SA         SA           107         5N         SA         SA           108         5R         SA         SA	96	3M	D16	D25	
99         3P         Q17         Q26           100         2N         D17         D26           101         2P         NC         D35           102         1P         NC         Q35           103         3R         SA         SA           104         4R         SA         SA           105         4P         SA         SA           106         5P         SA         SA           107         5N         SA         SA           108         5R         SA         SA	97	1N	NC	D34	
100         2N         D17         D26           101         2P         NC         D35           102         1P         NC         Q35           103         3R         SA         SA           104         4R         SA         SA           105         4P         SA         SA           106         5P         SA         SA           107         5N         SA         SA           108         5R         SA         SA	98	2M	NC	Q34	
101         2P         NC         D35           102         1P         NC         Q35           103         3R         SA         SA           104         4R         SA         SA           105         4P         SA         SA           106         5P         SA         SA           107         5N         SA         SA           108         5R         SA         SA	99	3P	Q17	Q26	
102         1P         NC         Q35           103         3R         SA         SA           104         4R         SA         SA           105         4P         SA         SA           106         5P         SA         SA           107         5N         SA         SA           108         5R         SA         SA	100	2N	D17	D26	
103         3R         SA         SA           104         4R         SA         SA           105         4P         SA         SA           106         5P         SA         SA           107         5N         SA         SA           108         5R         SA         SA	101	2P		D35	
104         4R         SA         SA           105         4P         SA         SA           106         5P         SA         SA           107         5N         SA         SA           108         5R         SA         SA	102	1P	NC	Q35	
104         4R         SA         SA           105         4P         SA         SA           106         5P         SA         SA           107         5N         SA         SA           108         5R         SA         SA	103	3R	SA	SA	
105         4P         SA         SA           106         5P         SA         SA           107         5N         SA         SA           108         5R         SA         SA		4R		SA	
106         5P         SA         SA           107         5N         SA         SA           108         5R         SA         SA					
107         5N         SA         SA           108         5R         SA         SA					
108 5R SA SA	107				
100 - IIILEIIIAI IIILEIIIAI	109	-	Internal	Internal	

#### Notes:

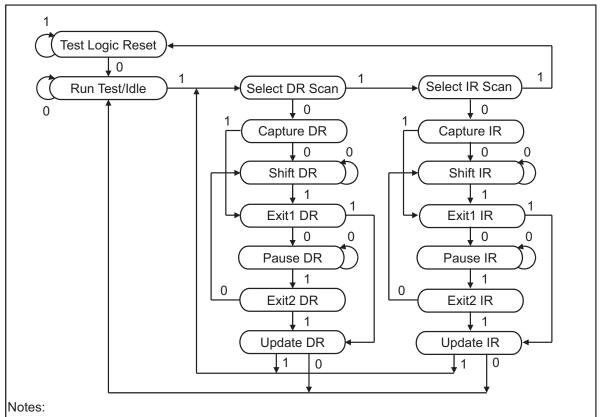
In boundary scan mode,

- 1. Clock balls (K, /K) are referenced to each other and must be at opposite logic levels for reliable operation.
- 2. CQ and /CQ data are synchronized to the K clock (except EXTEST, SAMPLE-Z).

### **ID Register**



# **TAP Controller State Diagram**



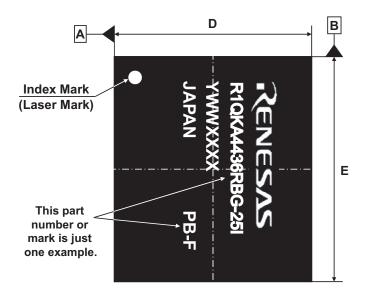
The value adjacent to each state transition in this figure represents the signal present at TMS at the time of a rising edge at TCK.

No matter what the original state of the controller, it will enter Test-Logic-Reset when TMS is held high for at least five rising edges of TCK.

# **Package Dimensions and Marking Information**

Both Pb parts and Pb-free parts are available.

JEITA Package Code	Renesas Code	Previous Code	Mass (typ.)
P-LBGA165-15x17-1.00	PLBG0165FD-B	165FHE-B	0.6g



# **Top View**

Marking Information

1st row: Vender name (RENESAS)

2nd row: Part number

3rd row: Y : Year code

WW : Week code

XXXX : Renesas

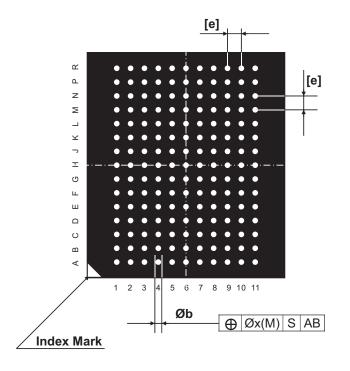
internal use

4th row: Country name (JAPAN)

+ "None" --- Pb parts

+ "PB-F" --- Pb-free parts





# **Bottom View**

Reference	Dimer	nsion ii	n mm
Symbol	Min	Nom	Max
D	14.9	15.0	15.1
Е	16.9	17.0	17.1
Α	-	-	1.4
A1	0.31	0.36	0.41
[e]	-	1.0	-
b	0.45	0.5	0.6
х	-	-	0.2
у	-	-	0.15

Revision History
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		Description		
Rev.	Date	Page	Page Summary	
Rev.1.00	'12.10.01	-	New Datasheet.	
Rev.2.00	'13.06.01	P29	Update : Package Dimensions and Marking Information	
Rev.2.01	'13.11.18	-	Туро.	
Rev.2.02	'14.08.01	P6	Modification : Pin Descriptions.	

QDR RAMs and Quad Data Rate RAMs comprise a new family of products developed by Cypress Semiconductor, and Renesas Electronics Corporation.

http://www.gdrconsortium.org/

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